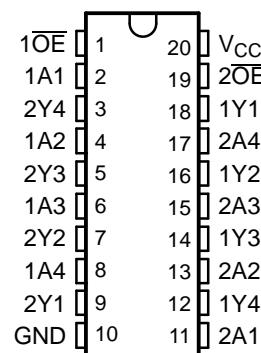


## FEATURES

- **Controlled Baseline**
  - One Assembly/Test Site, One Fabrication Site
- **Extended Temperature Performance of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree <sup>(1)</sup>**
- **2-V to 5.5-V  $V_{\text{CC}}$  Operation**
- **Max  $t_{\text{pd}}$  of 6.5 ns at 5 V**
- **Typical  $V_{\text{OLP}}$  (Output Ground Bounce)  $<0.8$  V at  $V_{\text{CC}} = 3.3$  V,  $T_A = 25^{\circ}\text{C}$**
- **Typical  $V_{\text{OHV}}$  (Output  $V_{\text{OH}}$  Undershoot)  $>2.3$  V at  $V_{\text{CC}} = 3.3$  V,  $T_A = 25^{\circ}\text{C}$**
- **Supports Mixed-Mode Voltage Operation on All Ports**
- **$I_{\text{off}}$  Supports Partial-Power-Down Mode Operation**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**

(1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

DW PACKAGE  
(TOP VIEW)



## DESCRIPTION/ORDERING INFORMATION

This octal buffer/line driver is designed for 2-V to 5.5-V  $V_{\text{CC}}$  operation.

The SN74LV244A-EP is designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device is organized as two 4-bit line drivers with separate output-enable ( $\overline{\text{OE}}$ ) inputs. When  $\overline{\text{OE}}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{\text{OE}}$  is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to  $V_{\text{CC}}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

## ORDERING INFORMATION

$T_A$	PACKAGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
$-55^{\circ}\text{C}$ to $125^{\circ}\text{C}$	SOIC – DW	Reel of 2000	SN74LV244AMDWREP

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# SN74LV244A-EP OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

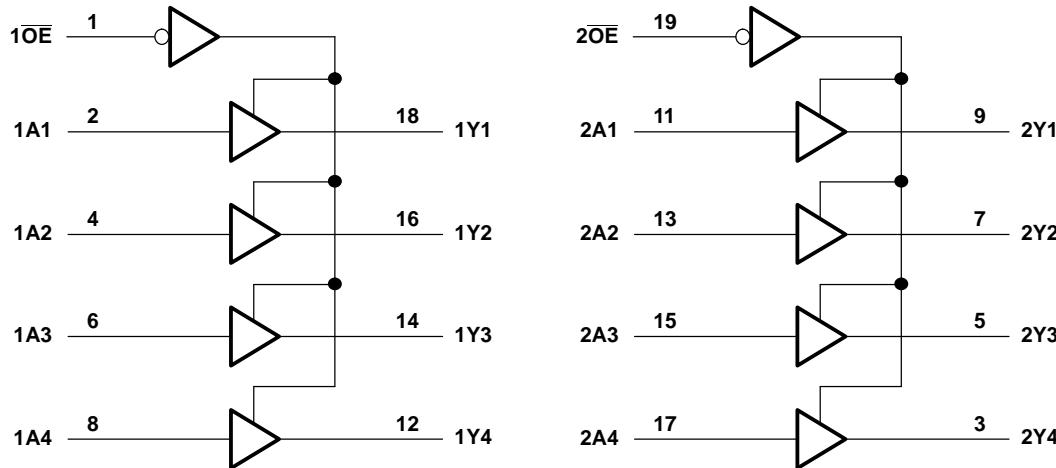
SCLS695—JANUARY 2006

TEXAS  
INSTRUMENTS  
www.ti.com

## FUNCTION TABLE (EACH BUFFER)

INPUTS		OUTPUT
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

## LOGIC DIAGRAM (POSITIVE LOGIC)



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage range	-0.5	7	V
$V_I$	Input voltage range <sup>(2)</sup>	-0.5	7	V
$V_O$	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	7	V
$V_O$	Output voltage range applied in the high or low state <sup>(2)(3)</sup>	-0.5	$V_{CC} + 0.5$	V
$I_{IK}$	Input clamp current $V_I < 0$		-20	mA
$I_{OK}$	Output clamp current $V_O < 0$		-50	mA
$I_O$	Continuous output current $V_O = 0$ to $V_{CC}$		$\pm 35$	mA
	Continuous current through $V_{CC}$ or GND		$\pm 70$	mA
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>		58	$^{\circ}\text{C}/\text{W}$
$T_{stg}$	Storage temperature range	-65	150	$^{\circ}\text{C}$

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) This value is limited to 5.5 V maximum.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

**Recommended Operating Conditions<sup>(1)</sup>**

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	2	5.5	V
$V_{IH}$	High-level input voltage	$V_{CC} = 2\text{ V}$	1.5	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	$V_{CC} \times 0.7$	
		$V_{CC} = 3\text{ V to }3.6\text{ V}$	$V_{CC} \times 0.7$	
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	$V_{CC} \times 0.7$	
$V_{IL}$	Low-level input voltage	$V_{CC} = 2\text{ V}$	0.5	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	$V_{CC} \times 0.3$	
		$V_{CC} = 3\text{ V to }3.6\text{ V}$	$V_{CC} \times 0.3$	
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	$V_{CC} \times 0.3$	
$V_I$	Input voltage	0	5.5	V
$V_O$	Output voltage	High or low state	0	$V_{CC}$
		3-state	0	5.5
$I_{OH}$	High-level output current	$V_{CC} = 2\text{ V}$	-50	$\mu\text{A}$
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-2	mA
		$V_{CC} = 3\text{ V to }3.6\text{ V}$	-8	
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-16	
$I_{OL}$	Low-level output current	$V_{CC} = 2\text{ V}$	50	$\mu\text{A}$
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	2	mA
		$V_{CC} = 3\text{ V to }3.6\text{ V}$	8	
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	16	
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	200	ns/V
		$V_{CC} = 3\text{ V to }3.6\text{ V}$	100	
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	20	
$T_A$	Operating free-air temperature	-55	125	$^{\circ}\text{C}$

(1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**SN74LV244A-EP**  
**OCTAL BUFFER/DRIVER**  
**WITH 3-STATE OUTPUTS**

SCLS695—JANUARY 2006

 **TEXAS**  
**INSTRUMENTS**  
[www.ti.com](http://www.ti.com)

**Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
V <sub>OH</sub>	I <sub>OH</sub> = -50 $\mu$ A	2 V to 5.5 V	V <sub>CC</sub> - 0.1			V
	I <sub>OH</sub> = -2 mA	2.3 V	2			
	I <sub>OH</sub> = -8 mA	3 V	2.48			
	I <sub>OH</sub> = -16 mA	4.5 V	3.8			
V <sub>OL</sub>	I <sub>OL</sub> = 50 $\mu$ A	2 V to 5.5 V		0.1		V
	I <sub>OL</sub> = 2 mA	2.3 V		0.4		
	I <sub>OL</sub> = 8 mA	3 V		0.44		
	I <sub>OL</sub> = 16 mA	4.5 V		0.55		
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V		$\pm 1$	$\mu$ A	
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V		$\pm 5$	$\mu$ A	
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	5.5 V		20	$\mu$ A	
I <sub>off</sub>	V <sub>I</sub> or V <sub>O</sub> = 0 to 5.5 V	0		5	$\mu$ A	
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		2.3	pF	

**Switching Characteristics**

over recommended operating free-air temperature range, V<sub>CC</sub> = 2.5 V  $\pm$  0.2 V (unless otherwise noted) (see [Figure 1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C			MIN	MAX	UNIT
				MIN	TYP	MAX			
t <sub>pd</sub>	A	Y	C <sub>L</sub> = 50 pF		9.5	15.3	1	18	ns
	$\overline{OE}$	Y			10.8	17.8	1	21	ns
	$\overline{OE}$	Y			13.4	19.2	1	21	ns
						2		2	ns

**Switching Characteristics**

over recommended operating free-air temperature range, V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V (unless otherwise noted) (see [Figure 1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C			MIN	MAX	UNIT
				MIN	TYP	MAX			
t <sub>pd</sub>	A	Y	C <sub>L</sub> = 50 pF		6.8	11.9	1	13.5	ns
	$\overline{OE}$	Y			7.8	14.1	1	16	ns
	$\overline{OE}$	Y			11	16	1	18	ns
						1.5		1.5	ns

## Switching Characteristics

over recommended operating free-air temperature range,  $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$  (unless otherwise noted) (see [Figure 1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			MIN	MAX	UNIT
				MIN	TYP	MAX			
$t_{pd}$	A	Y	$C_L = 50 \text{ pF}$	4.9	7.5	1	8.5	ns	
$t_{en}$	$\overline{OE}$	Y		5.6	9.3	1	10.5	ns	
$t_{dis}$	$\overline{OE}$	Y		8.8	14.2	1	15.5	ns	
$t_{sk(o)}$					1		1	ns	

## Noise Characteristics<sup>(1)</sup>

$V_{CC} = 3.3 \text{ V}$ ,  $C_L = 50 \text{ pF}$ ,  $T_A = 25^\circ\text{C}$

PARAMETER		MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic $V_{OL}$		0.55		V
$V_{OL(V)}$	Quiet output, minimum dynamic $V_{OL}$		-0.5		V
$V_{OH(V)}$	Quiet output, minimum dynamic $V_{OH}$		2.9		V
$V_{IH(D)}$	High-level dynamic input voltage		2.31		V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

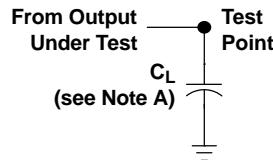
(1) Characteristics are for surface-mount packages only.

## Operating Characteristics

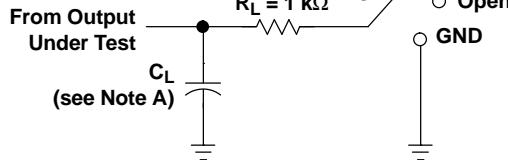
$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	$V_{CC}$	TYP	UNIT
		3.3 V	14	pF
$C_{pd}$	$C_L = 50 \text{ pF}$ , $f = 10 \text{ MHz}$	5 V	16	

**PARAMETER MEASUREMENT INFORMATION**

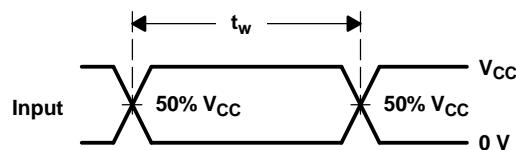


LOAD CIRCUIT FOR  
 TOTEM-POLE OUTPUTS

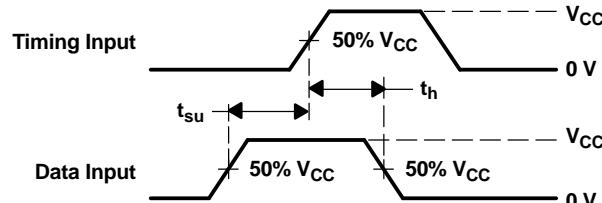


LOAD CIRCUIT FOR  
 3-STATE AND OPEN-DRAIN OUTPUTS

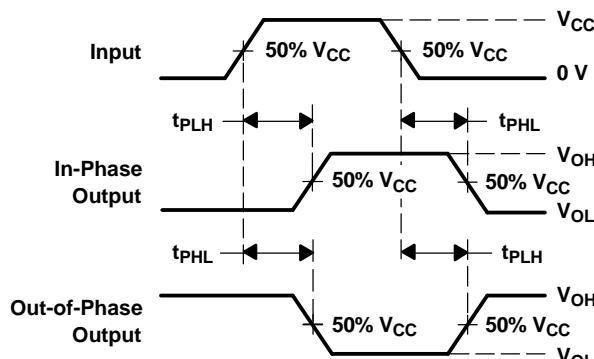
TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{CC}$
$t_{PHZ}/t_{PZH}$	GND
Open Drain	$V_{CC}$



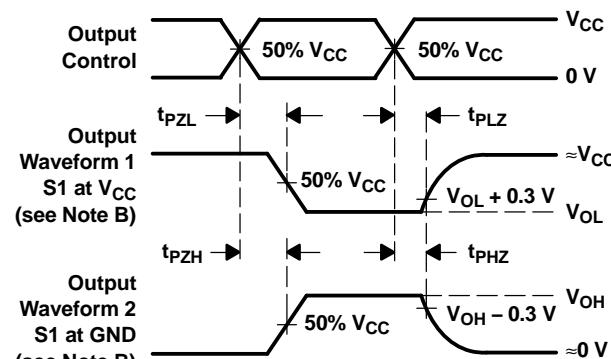
VOLTAGE WAVEFORMS  
 PULSE DURATION



VOLTAGE WAVEFORMS  
 SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
 PROPAGATION DELAY TIMES  
 INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS  
 ENABLE AND DISABLE TIMES  
 LOW- AND HIGH-LEVEL ENABLING

NOTES:

- $C_L$  includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics:  $PRR \leq 1 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 3 \text{ ns}$ ,  $t_f \leq 3 \text{ ns}$ .
- The outputs are measured one at a time, with one input transition per measurement.
- $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .
- All parameters and waveforms are not applicable to all devices.

**Figure 1. Load Circuits and Voltage Waveforms**

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LV244AMDWREP	Obsolete	Production	SOIC (DW)   20	-	-	Call TI	Call TI	-55 to 125	LV244AMEP

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**OTHER QUALIFIED VERSIONS OF SN74LV244A-EP :**

- Catalog : [SN74LV244A](#)

- Automotive : [SN74LV244A-Q1](#)

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NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

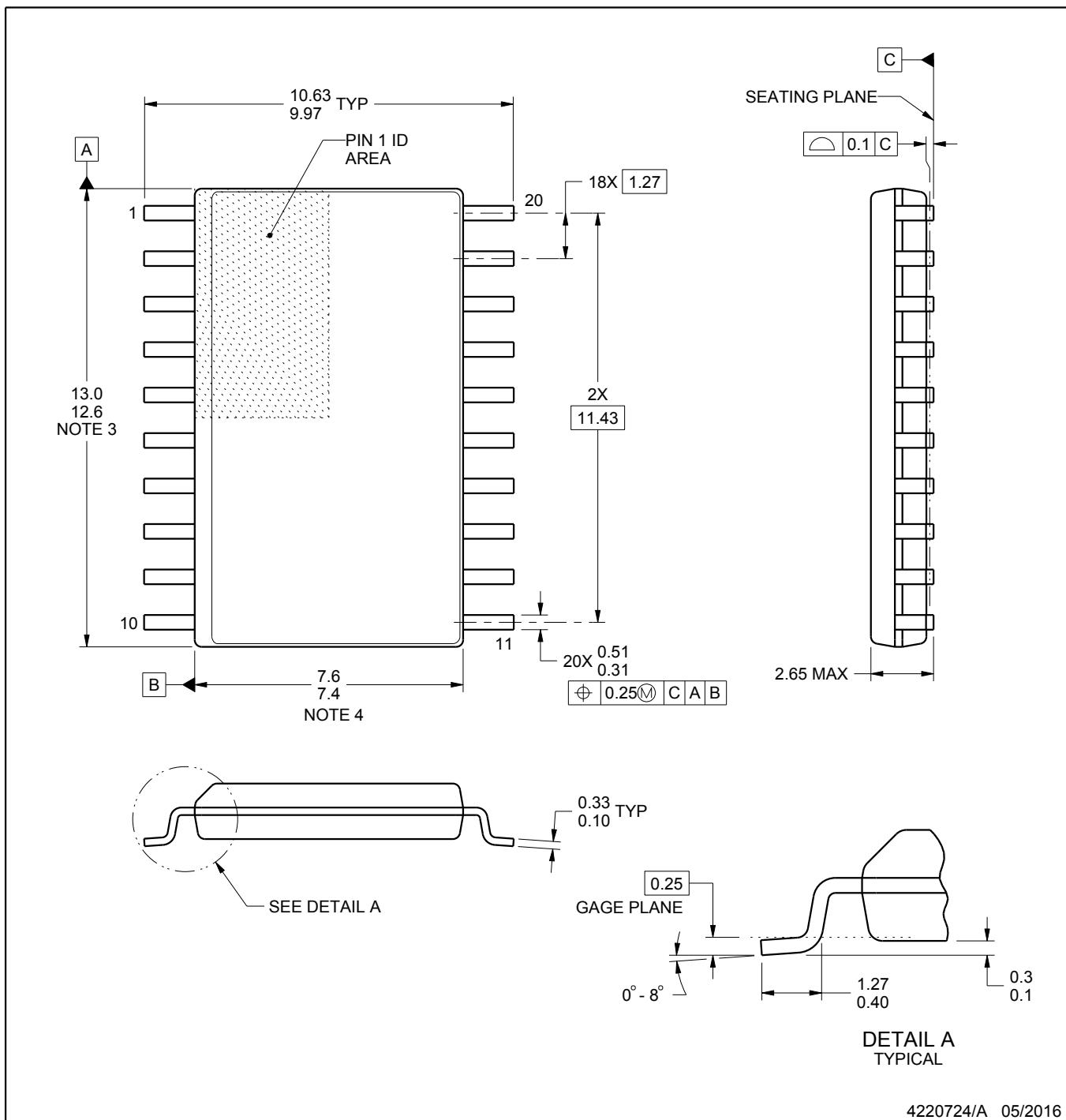
# PACKAGE OUTLINE

DW0020A



SOIC - 2.65 mm max height

SOIC



## NOTES:

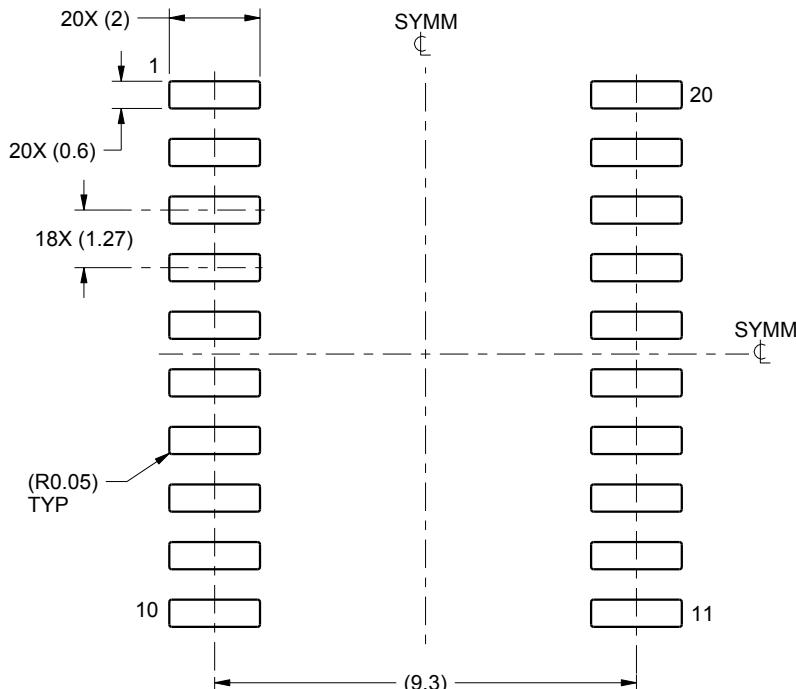
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

# EXAMPLE BOARD LAYOUT

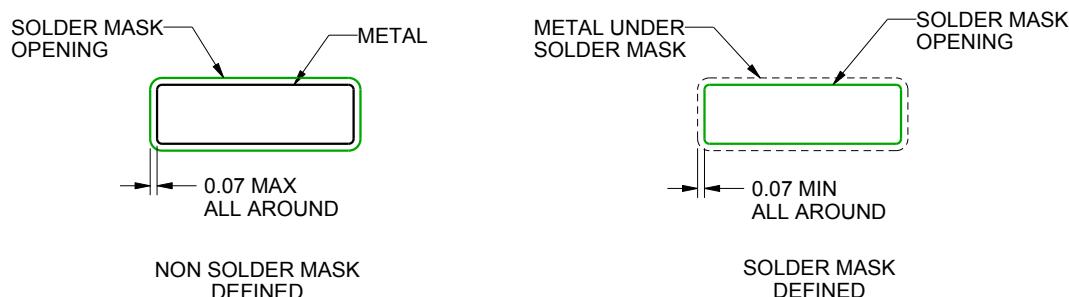
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

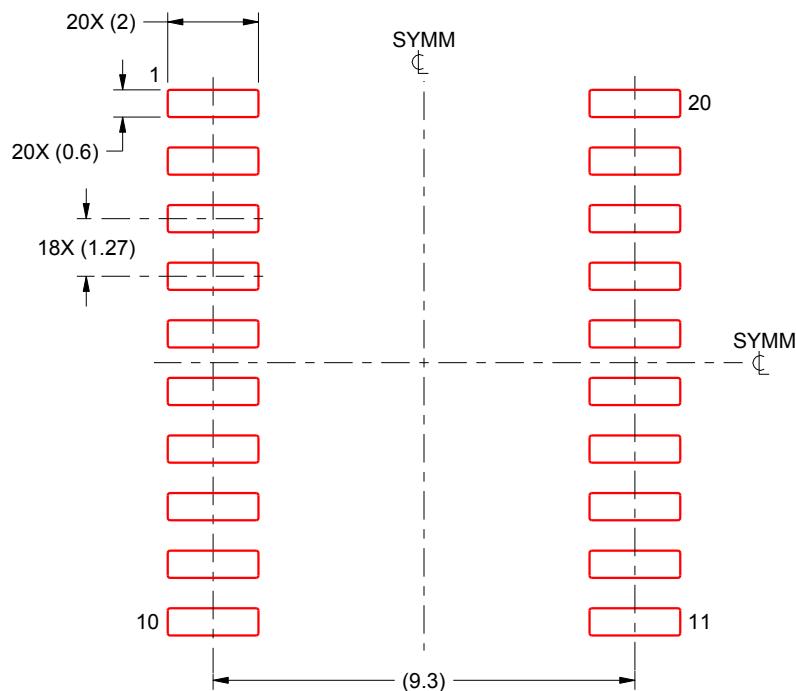
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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